

TIG067SS



IGBT

400V, 150A, VCE(sat);3.8V Single N-Channel

ON Semiconductor®

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Features

- Low-saturation Voltage
- Enhancement Type
- High Speed Switching
- 4.0V Drive
- Built-in Gate-to-Emitter Protection Diode
- Pb-Free, Halogen Free and RoHS Compliance

Applications

- Light-controlling Flash

Specifications

Absolute Maximum Ratings at Ta=25°C

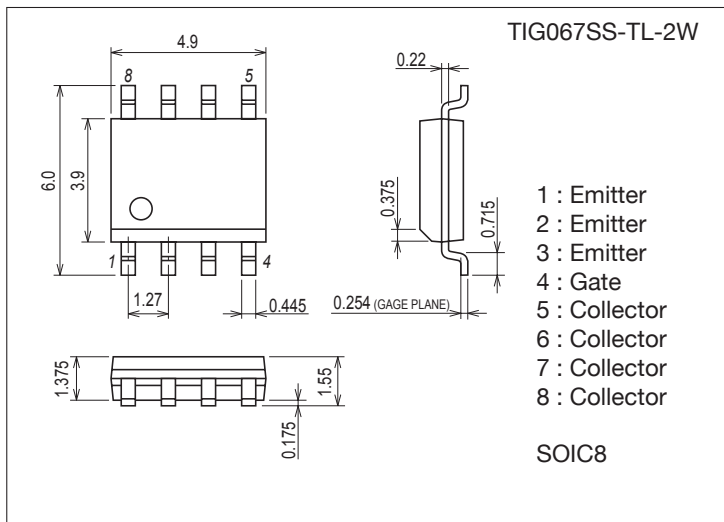
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Emitter Voltage (DC)	V _{CES}		400	V
Collector-to-Emitter Voltage (Pulse)	V _{CESP}	PW≤1ms	450	V
Gate-to-Emitter Voltage (DC)	V _{GES}		±6	V
Gate-to-Emitter Voltage (Pulse)	V _{GESP}	PW≤1ms	±8	V
Collector Current (Pulse)	I _{CP}	C _M =600μF	150	A
Maximum Collector-to-Emitter dv / dt	dv / dt	V _{CE} ≤320V, starting T _{ch} =25°C	1500	V / μs
Allowable Power Dissipation	P _D	When mounted on FR4 substrate (11,680mm ² ×1.6mm)	1.2	W
Channel Temperature	T _{ch}		150	°C
Storage Temperature	T _{stg}		-40 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ)

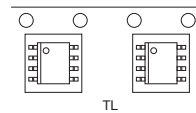
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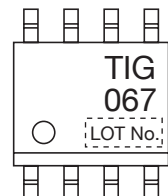
Product & Package Information

- Package : SOIC8
- JEITA, JEDEC : SC-87, SOT-96
- Minimum Packing Quantity : 2500 pcs./reel

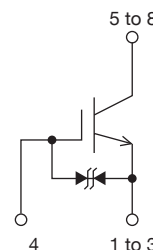
Packing Type: TL



Marking



Electrical Connection



ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

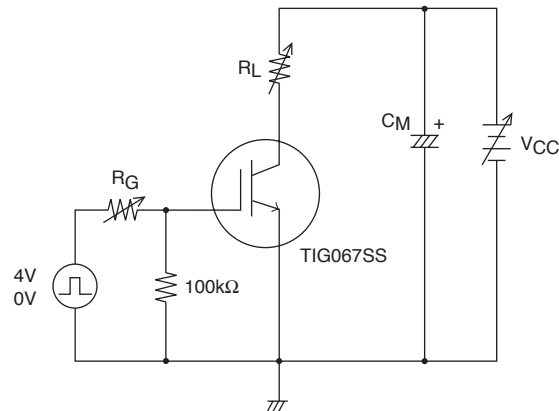
TIG067SS

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Breakdown Voltage	V(BR)CES	IC=2mA, VGE=0V	400			V
Collector-to-Emitter Cutoff Current	ICES	VCE=320V, VGE=0V			10	μA
Gate-to-Emitter Leakage Current	IGES	VGE=±6V, VCE=0V			±10	μA
Gate-to-Emitter Threshold Voltage	VGE(off)	VCE=10V, IC=1mA	0.4		1.0	V
Collector-to-Emitter Saturation Voltage	VCE(sat)	IC=150A, VGE=4V		3.8	5	V
Input Capacitance	Cies	VCE=10V, f=1MHz		5100		pF
Output Capacitance	Coes				59	pF
Reverse Transfer Capacitance	Cres				43	pF
Fall Time	tf	IC=150A, VCC=320V, Resistor load VGE=4V, RG=36Ω		270		ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Fig1 Large Current R Load Switching Circuit

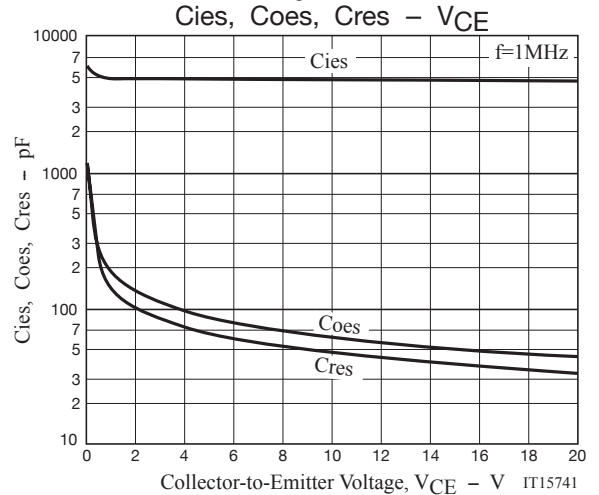
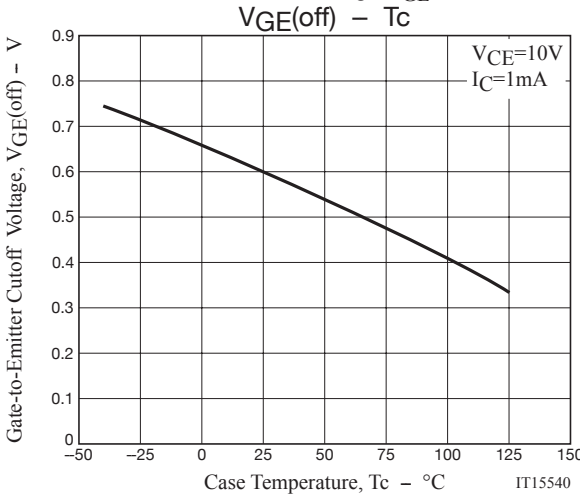
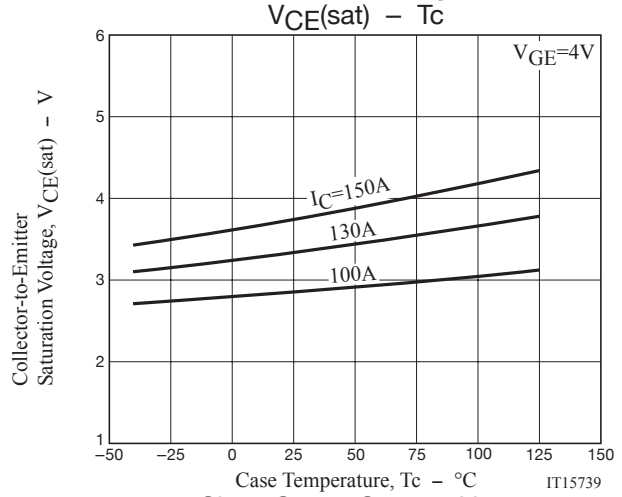
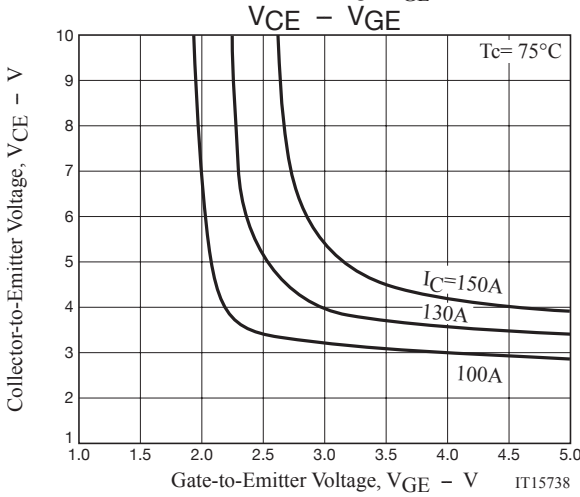
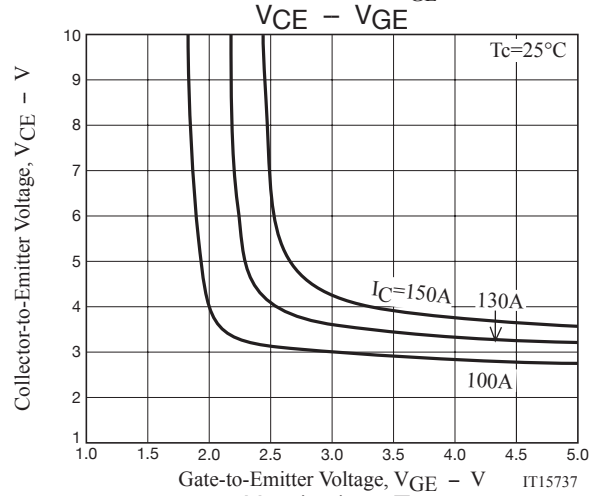
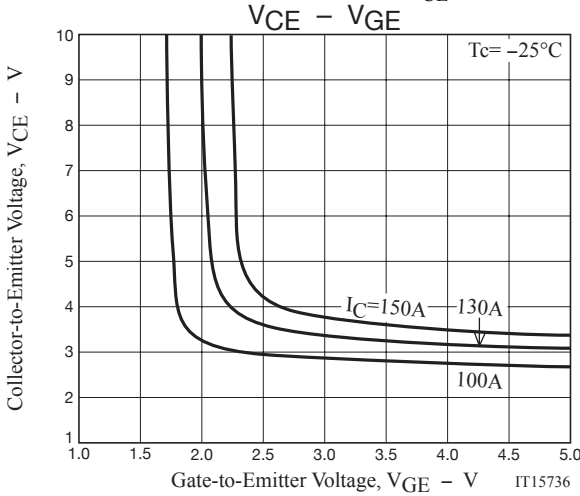
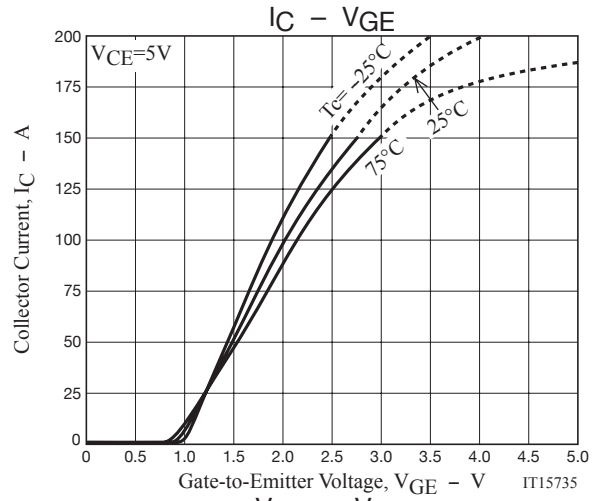
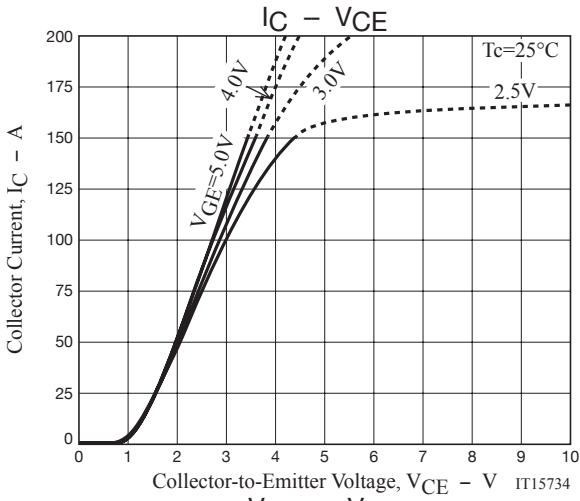


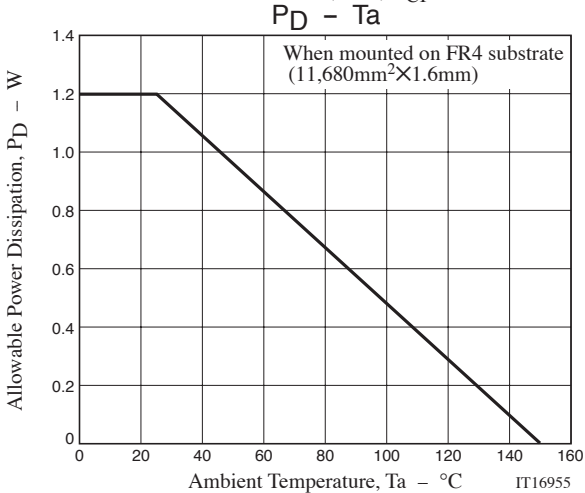
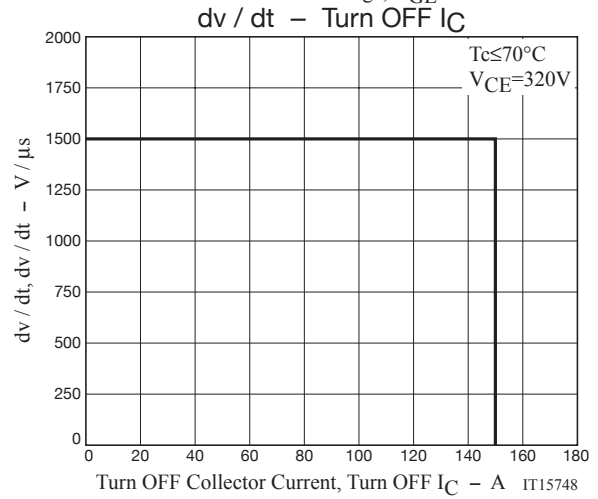
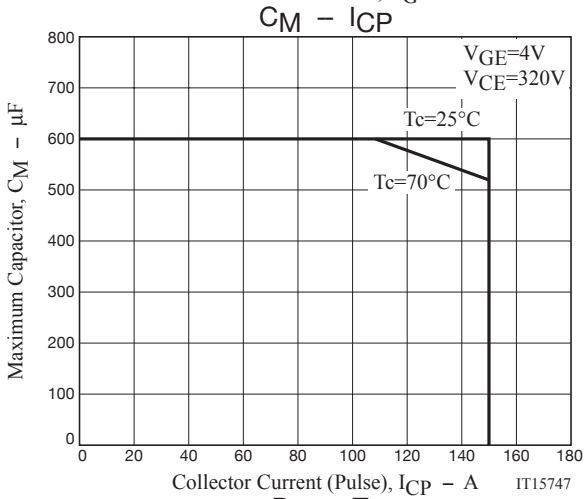
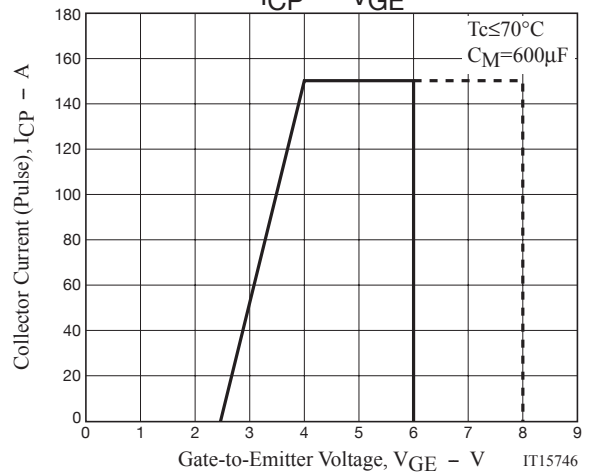
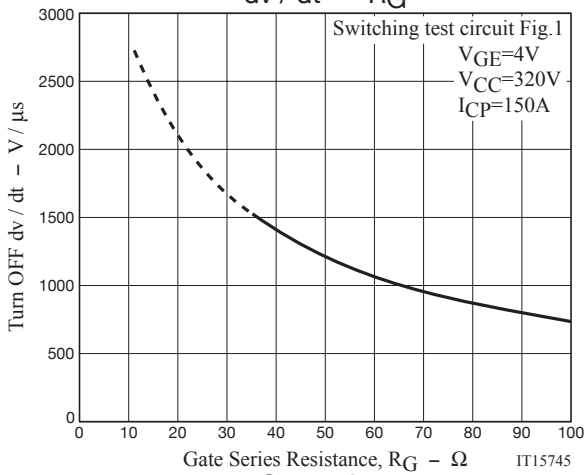
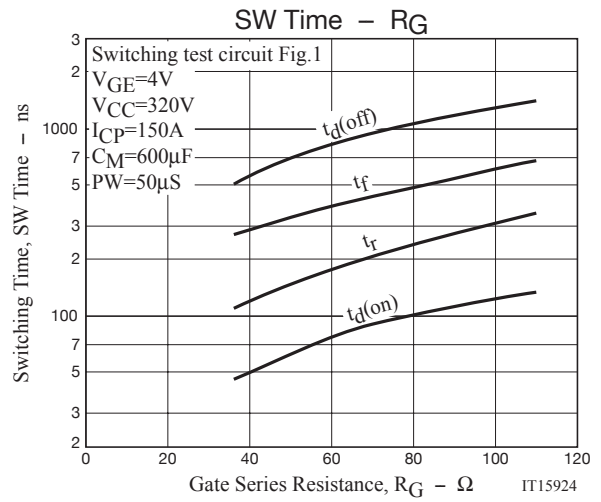
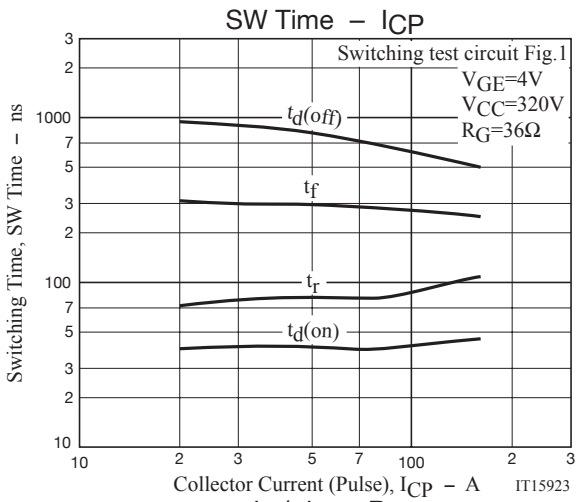
Note1. Gate Series Resistance $R_G \geq 36\Omega$ is recommended for protection purpose at the time of turn OFF. However, if $dv/dt \leq 1500/\mu s$ is satisfied at customer's actual set evaluation, $R_G < 36\Omega$ can also be used.

Note2. The collector voltage gradient dv/dt must be smaller than $1500V/\mu s$ to protect the device when it is turned off.

ORDERING INFORMATION

Device	Package	Shipping	memo
TIG067SS-TL-2W	SOIC8	2,500pcs./reel	Pb-Free and Halogen Free



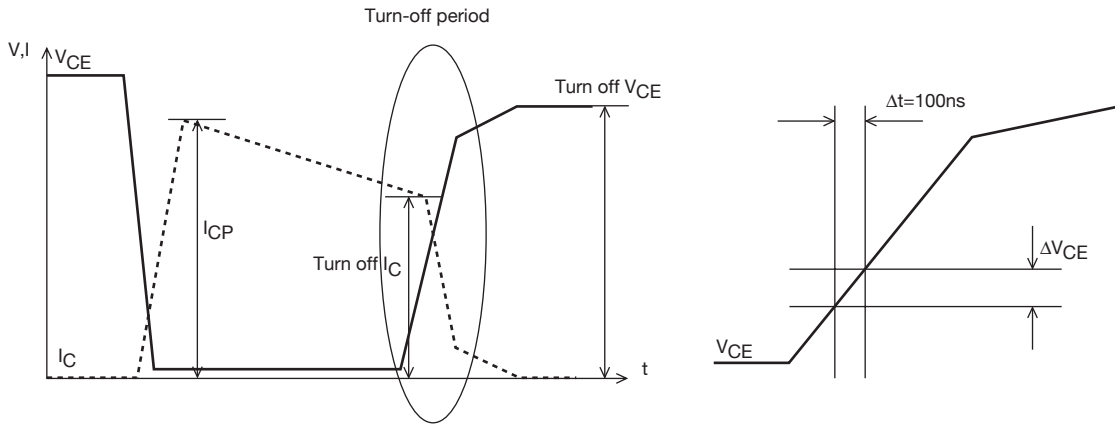


Definition of dv/dt

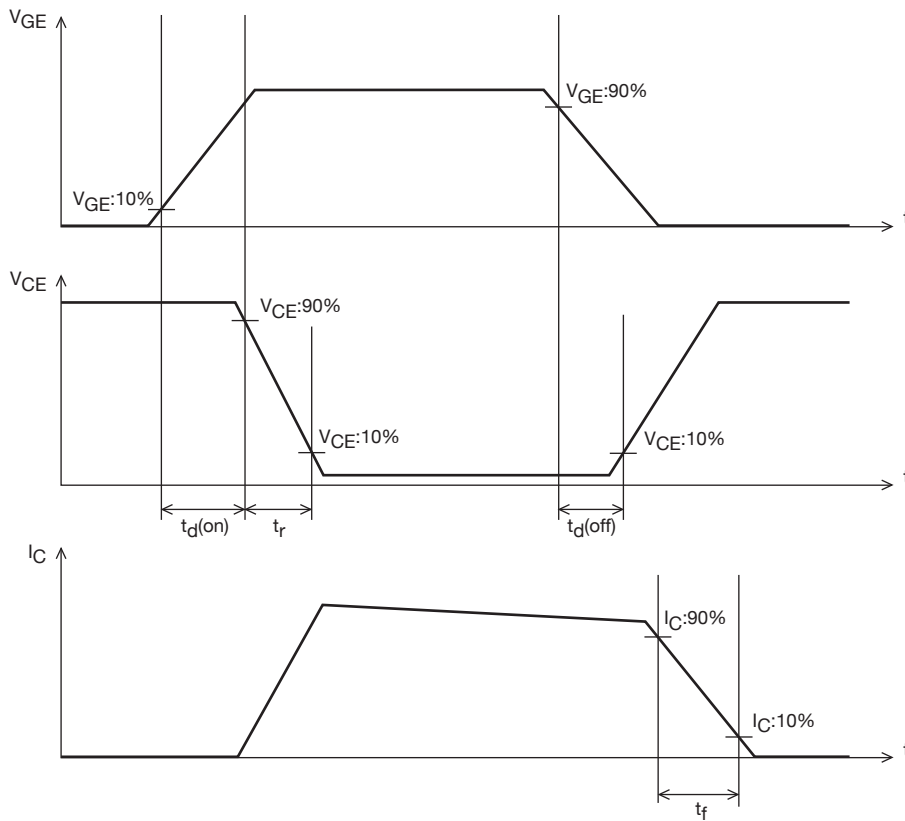
dv/dt is defined as the maximum slope of the below V_{CE} curve during turn-off period.
 $dv/dt = \Delta V_{CE} / \Delta t = \Delta V_{CE} / 100ns$

Overall waveform

Enlarged picture of turn-off period



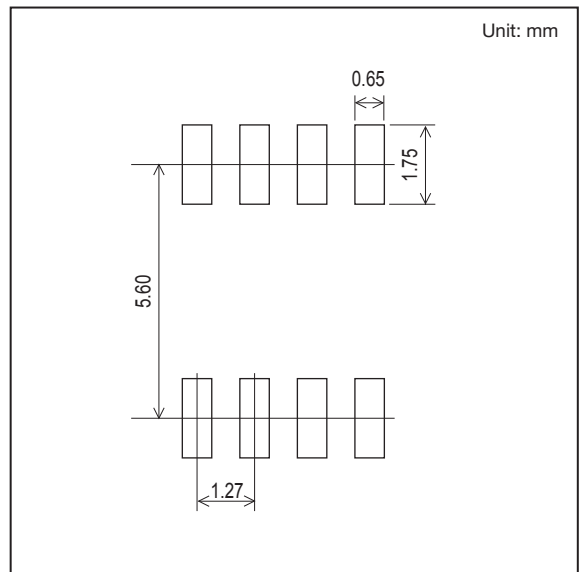
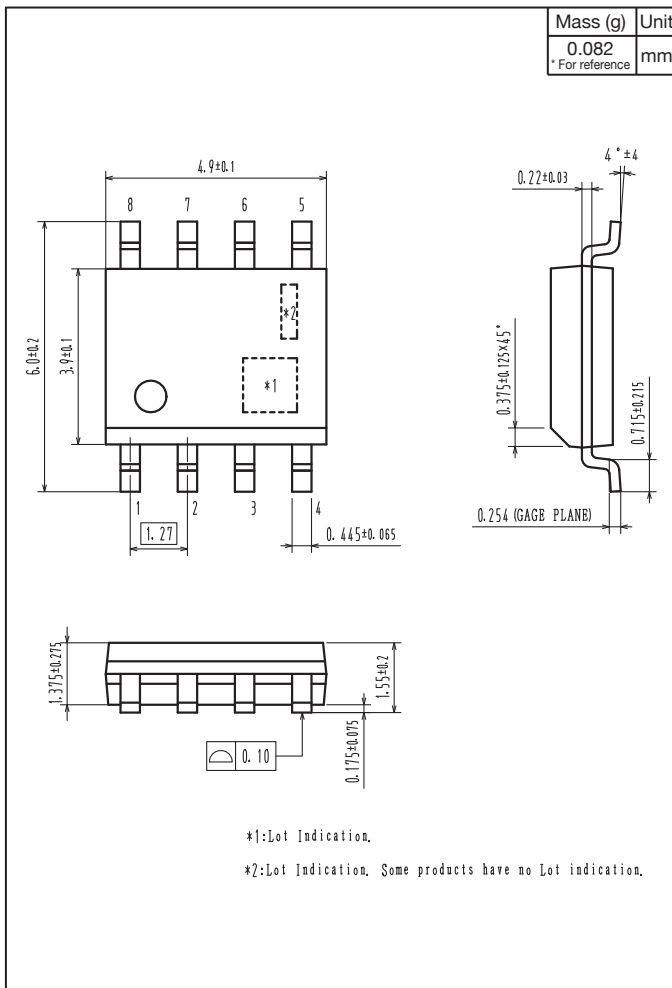
Definition of Switching Time



TIG067SS

Outline Drawing TIG067SS-TL-2W

Land Pattern Example



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